

Erik Jonsson School of Engineering and Computer Science

***Static and Dynamic Characterization
of a 3.3 kV, 45 A 4H-SiC MOSFET***

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Citation:

Anurag, A., G. Gohil, S. Acharya, K. Han, et al. 2018. "Static and dynamic characterization of a 3.3 kV, 45 A 4H-SiC MOSFET." *Materials Science Forum* 924: 739-742, doi: 10.4028/www.scientific.net/MSF.924.739

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